



SWITCH MODE POWER SUPPLY WITH FEED-FORWARD PULSE LIMIT CONTROL

BACKGROUND OF THE INVENTION

5 The invention relates to a switch mode power supply (SMPS). In particular, the invention relates to a SMPS that derives a rectified input supply voltage from an AC, mains supply voltage to produce an output supply voltage.

10 Recently, an interest has evolved for revising European Standard EN60 555-2 for the purpose of reducing the permissible low frequency harmonic content of the waveform of the input mains supply current and increase the power factor. It may be desirable to reduce the low frequency harmonic content of the waveform of the input current without significantly increasing
15 a ripple voltage in the output supply voltage.

SUMMARY OF THE INVENTION

In a switch-mode power supply, embodying an aspect of the invention, a first plurality of current pulses at high
20 frequency are produced from an input mains supply current. The amplitude of the first plurality of current pulses varies in accordance with a waveform of an unfiltered, full-wave-rectified mains supply voltage in a manner to reduce distortion in the input mains supply current. To reduce ripple component at an output of
25 the power supply that is caused by the amplitude variations of the first plurality of current pulses, a second plurality of current pulses are generated in, for example, an interleaving manner with respect to the first plurality of current pulses and applied to the output. The second plurality of current pulses are pulse-width
30 modulated in accordance a feedback signal that is indicative of a ripple component. The unfiltered, full wave rectified mains supply voltage produces in a feed-forward manner pulse-width modulation of the second plurality of current pulses so as to improve overall ripple component reduction.

35 In accordance with an aspect of the invention, the full, unfiltered, full-wave-rectified mains supply voltage produces variation of the upper limit of the pulse-width of the first plurality of current pulses during the period of the mains supply

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☒	Description : paged ...1... to paged ...12...	
☒	Claim(s) : paged ...13... to paged ...15...	
☒	Drawing(s) : paged ...17... to paged ...17...	
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voltage in a feed-forward manner. In this way, the maximum pulse-width is larger, during a portion of the period when the mains supply voltage is smaller than its peak value than when it is at its peak value. Thus, increase regulation range is obtained without exceeding the allowed stress in components of the power supply relative to a situation in which the upper limit to the pulse-width is the same throughout the period of the mains supply voltage.

A switch mode power supply, embodying an aspect of the invention, includes a source of an AC, mains supply voltage, an inductance and a first rectifier coupled to the mains source for rectifying the mains supply voltage to apply to the inductance a rectified, first supply voltage. Pulse-width modulated current pulses are generated in the inductance from the first supply voltage at a frequency that is substantially higher than a frequency of the mains supply voltage. The current pulses are coupled from the inductance to a load circuit to energize the load circuit. A pulse-width modulator is responsive to a feedback signal for generating the switching signal in accordance with the feedback signal. A pulse-width of the switching signal is limited such that a limit associated with the pulse-width varies during a period of the mains supply voltage in accordance with a waveform of the mains supply voltage.

BRIEF DESCRIPTION OF THE DRAWINGS

FIGURE 1 illustrates an SMPS, embodying an aspect of the invention, that utilizes a current super-position technique;

FIGURES 2a-2h illustrate waveforms useful for explaining the operation of the SMPS of FIGURE 1;

FIGURES 3a-3c illustrate additional waveforms useful for explaining the operation of the SMPS of FIGURE 1;

FIGURE 4 illustrates a second embodiment of the invention;

FIGURES 5a-5e illustrate waveforms useful for explaining the operation of the arrangement of FIGURE 4;

FIGURE 6 illustrates a graph providing the input power factor in the arrangement of FIGURE 4; and



FIGURE 7 illustrates a graph providing the harmonics content of the input current in the arrangement of FIGURE 4.

DETAILED DESCRIPTION OF THE DRAWINGS

5 FIGURE 1 illustrates an SMPS 100, embodying an aspect of the invention, that utilizes a technique, referred to herein as current super-position technique. SMPS 100 of FIGURE 1 is suitable for providing, for example, 120 watts power. A mains supply voltage source 107 that produces an AC voltage VM is coupled to a full-wave bridge rectifier 102 that produces an AC full-wave rectified input supply voltage V1 in a relatively small filter capacitor C1. AC voltage VM of source 107 is sinusoidal at, for example, a line frequency of 50 Hz. Because of the small capacitance of capacitor C1, low frequency harmonics of voltage V1 are not filtered out by capacitor C1. Voltage V1, having a waveform of an unfiltered, full wave rectified sinusoidal voltage, is coupled via a switching diode D1 to an end terminal W2a of a primary winding W1 of a flyback transformer T.

10 A switching signal V9, having a controllable frequency and duty cycle, is coupled via a resistor R3 to a resistor R14 and to a gate of an MOS switching transistor Q1 to turn on transistor Q1 only when signal V9 is at a HIGH level or 12 volts. The drain electrode of transistor Q1 is coupled to the other end terminal of winding W1. Signal V9 is developed at an output terminal of an integrated circuit (IC) 103 of the type TDA4605 operating as a pulse-width modulator. The frequency of signal V9 is selected to be within a range of 20-50 KHz.

15 In a given cycle of signal V9, after signal V9 attains the HIGH level, a pulse current i_{p1} flows through diode D1. An upramping current i_p that is equal to current i_{p1} in diode D1 is produced in winding W1, storing magnetic energy in transformer T. Immediately after signal V9 changes from the HIGH to a LOW level, transistor Q1 becomes non-conductive and a flyback operation occurs. The result is that flyback pulse currents are produced in secondary windings W2, W3, W4 and W5 of transformer T. The drain voltage of transistor Q1 is limited, during flyback, by means of a snubber circuit, not shown.



As a result of flyback current pulses, such as a current pulse is⁴ in winding W4, that are produced from pulses ip, DC output supply voltages V3, V4, V5 and V8 are produced in capacitors C3, C4, C5 and C8 via rectifying diodes D3, D4, D5 and D8, respectively. Voltage V4 energizes, for example, a horizontal deflection output stage 37 and voltage V5 energizes, for example, an audio stage of a television receiver.

Transformer T isolates, with respect to electrical shock hazard, source 107 and a "hot" ground conductor, H, from a "cold" ground conductor G. Voltages V3 and V8 are referenced to hot ground conductor H. Whereas, voltages V4 and V5 are referenced to cold ground conductor G.

In normal operation, a DC sense voltage V30 that is indicative of, for example, voltage V4 is produced in a circuit 30 by filtering and rectifying the flyback pulses in winding W3 and voltage dividing. A resistor 30a is adjustable for adjusting the output supply voltages by the adjustment of voltage V30. Sense voltage V30 is applied to a sense input terminal, pin 1, of IC 103. Voltage V30 is compared in IC 103 with a reference voltage 103a. An error voltage 103b is produced from a difference between voltage V30 and reference voltage 103a. Error voltage 103b is coupled to an input of a stop comparator 103c to control a pulse-width or a HIGH-to-LOW transition of signal V9 to regulate the levels of output voltages V4 and V5.

Voltage V1 is also coupled via a series arrangement of a resistor R13 and a rectifying diode D2 to a filter capacitor C2 for producing a supply voltage V2 in capacitor C2. Voltage V2 is a constant, DC voltage that is proportional to the peak voltage of voltage V1. Voltage V2 is coupled via an MOS switching transistor Q2 and a switching diode D6, when transistor Q2 is conductive, to junction terminal W2a. Terminal W2a is coupled between diode D1 of winding W1 and a secondary winding W2 of transformer T.

DC voltage V8 developed, during flyback, via winding W2 is larger by about 15V than voltage V2. Voltage V8 is coupled to the gate of transistor Q2 via a resistor R8 and a resistor R12, coupled in series, to turn on switching transistor Q2 when a transistor Q3 that is coupled to the gate of transistor Q2 is turned off. By being larger than voltage V2, voltage V8 is sufficient to



turn on MOS transistor Q2. A protection diode D7 coupled between the source electrode and gate electrode of transistor Q2 limits gate-source voltage excursions of transistor Q2.

Signal V9 of FIGURE 1 also controls the switching operation frequency of transistor Q2. To control the switching operation of transistor Q2, signal V9 of FIGURE 1 is coupled via a diode D9 to a ramp generator that is formed by a resistor R7 and a capacitor C7. A zener diode D10 limits the maximum voltage of a ramp signal V7 in capacitor C7 to 9.1 volt. When signal V9 is HIGH, diode D9 is reverse biased and capacitor C7 is charged by means of voltage V2 through resistor R7. Consequently, signal V7 in capacitor C7 increases linearly. When signal V9 becomes LOW, diode D9 conducts and capacitor C7 is immediately discharged through the low impedance output formed at pin 5 of IC 103.

FIGURES 2a-2h illustrate waveforms useful for explaining the operation of the circuit of FIGURE 1. Similar symbols and numerals in FIGURES 1 and 2a-2h indicate similar items or functions.

The pulse width of signal V9 of FIGURE 1 determines the peak level of signal V7 that is developed in capacitor C7. Because the voltage that is coupled via diode D1 to winding W1 has a full wave rectified sinusoid waveform, the feedback signal to IC 103 causes the pulse width of signal V9 to vary as a function of full wave rectified voltage V1. Consequently, the peaks or envelope of signal V7 also varies as a function of voltage V1, during the 10 millisecond period of voltage V1, as shown in FIGURE 2d. In FIGURE 2d, for example, the ratio between the period of signal V7 and that of voltage V1 of FIGURE 2a is exaggerated for better clarity.

Signal V7 of FIGURE 1 is applied to an inverting input terminal of a comparator formed by a transistor Q4 and a transistor Q5. A resistor R5 produces emitter currents in transistors Q4 and Q5. A collector resistor R4 of transistor Q4 develops an output signal V10 at an output terminal 13a of the comparator.

Output signal V10 is coupled to the base of transistor Q3 to control switching operation of transistor Q3. The collector of transistor Q3 is coupled to a load arrangement formed by resistors



R8 and R12 and energized by supply voltage V8 to develop a switching signal V12 at the gate of transistor Q2.

Immediately after the transition to the HIGH level of signal V9, diode D1 becomes conductive and current i_{p1} is generated. As long as transistor Q2 remains turned off, current i_{p2} is not generated. Transistor Q2 remains nonconductive as long as output signal V10 of the comparator is HIGH in a manner to turn on transistor Q3 and, thereby, to turn off transistor Q2. Each of primary current i_{p1} and signal V7 increases in an upramping manner after signal V9 becomes HIGH.

During a given switching period of signal V9, when signal V7 of FIGURE 2d reaches a higher level than a threshold voltage V11 of the comparator, comparator output signal V10 of FIGURE 2e changes from the HIGH to the LOW level. When signal V10 attains the LOW level, transistor Q3 of FIGURE 1 is turned off and transistor Q2 is turned on by means of signal V12 of FIGURE 2f.

When transistor Q2 becomes conductive, diode D6 of FIGURE 1 becomes conductive causing diode D1 to become nonconductive. Therefore, input supply voltage V1 is decoupled from winding W1 and voltage V2 is coupled to winding W1 via transistor Q2. Primary current i_{p2} of FIGURE 2g in diode D6 of FIGURE 1 causes current i_p to continue flowing without a gap of time from the time the pulse of current i_{p1} ceases, as shown in FIGURES 2g and 2h.

After a predetermined interval that is determined in accordance with voltage V30 by IC 103 of FIGURE 1, signal V9 changes again to the LOW level that causes signal V7 to become LOW. Signal V9 is also coupled via a diode D13 to junction terminal 13a between resistor R4 and resistor R10. Diode D13 conduct when signal V9 is at the LOW level. Immediately after signal V9 becomes LOW, signal V10 of Figure 2e is forced to be LOW because diode D13 of FIGURE 1 conducts. Therefore, transistors Q1 and Q3 are turned off. Transistor Q2 does not conduct current although signal V12 at the collector of transistor Q3 is HIGH because transistor Q1 is turned off. Advantageously, because of the operation of diode D13, no current flows in resistors R8 and R12 when signal V9 is LOW. The resulting



reduction in power dissipation is about 2.5 watts at 120 watts input power. Diodes D9 and D13 are turned off when signal V9 becomes HIGH and a new cycle begins.

5 Primary current i_p that is determined by the superposition of currents i_{p1} and i_{p2} is shown in FIGURE 3a for a 100 watts input power. A resulting mains current i_M has a waveform that is shown in FIGURE 3b as a solid line. For comparison purposes, the broken line waveform in FIGURE 3b corresponds to
10 large filter capacitance at the output of the bridge rectifier for the same input power rate of a 100 watts. In each half-period of voltage V_M , the peaks of the pulses of current i_{p1} vary predominantly in a sinusoidal manner at the fundamental mains frequency. Capacitor C2 is charged via resistor R13 only in the
15 vicinity of the peaks of mains voltage V_M .

Advantageously, resistor R13 causes an increase in the conduction interval of the diodes of bridge rectifier 102; thereby, resistor R13 reduces the rate of change and peak amplitude of charging current i_3 , as illustrated in FIGURE 3b. Thus,
20 advantageously, high harmonics contents of current i_M such as at the 3rd, 5th, 7th, 9th and 11th harmonics is reduced. The peak value of the pulses of current i_3 is low, because the energy stored in capacitor C2 supplies only a portion of primary current i_p . About 65% of the power consumption is obtained by means of
25 current i_{p1} and 35% by means of current i_{p2} .

Threshold voltage V11 controls the ratio between the pulse-width of the pulse of current i_{p2} and that of the pulse of current i_{p1} . Because of a ripple voltage contained in voltage V30 during a given period of full wave rectified voltage V1, each of the
30 pulse-width of pulse-width modulated signal V9 and the peak of signal V7 is approximately at a maximum when voltage V1 is zero and at a minimum when voltage V1 is at a maximum. To establish threshold voltage V11 for the comparator formed by transistors Q4 and Q5, signal V7 is coupled via a diode D12 to a
35 parallel arrangement of a resistor R9 and a capacitor C10. A voltage developed in capacitor C10 varies in accordance with the low frequency envelope of the peaks of signal V7; whereas, the high frequency component is filtered out. The voltage in capacitor



C10 is coupled via a diode D11 to a capacitor C9 and to a base electrode of transistor Q5. Diode D11 and capacitor C9 operate as a minimum level detector for detecting the minimum value of the envelope of the peaks of signal V7. A forward voltage in diode D12 is temperature compensated by the opposite forward voltage developed in diode D11. The envelope of the peaks of signal V7 varies as a function of voltage V1. Slice level or threshold voltage V11 that is developed in capacitor C9 is determined by the minimum pulse-width of signal V9 within a period of voltage V1. Voltage V11 is applied to the noninverting input of the comparator formed by transistors Q4 and Q5.

For constant loading, the level of voltage V11 is relatively constant. Therefore, the pulse-width of each of the pulses of current i_{p1} is the same. Whereas, advantageously, the pulse-width of the pulses of current i_{p2} varies from a maximum, when voltage V1 is zero, to a minimum, when voltage V1 is at a peak.

Increased loading, for example, causes, in each period of signal V9, an increase in the pulse-width of signal V9. Thus, the minimum pulse-width of signal V9 also increases that tends to cause an increase in voltage V11. The increase in voltage V11 tends to delay the instant, during each pulse of signal V9, when signal V10 becomes LOW, and, therefore, when transistor Q2 becomes conductive. The result is an increase in the pulse-width of the pulse of current i_{p1} . Since the pulse-width of signal V9 also increases, a ratio between the length of the conduction interval of transistor Q2 and that of transistor Q1 tends to vary less than if, for example, voltage V11 were a constant voltage. Therefore, advantageously, the ripple voltage of output voltage V4 is less affected by loading variations than if voltage V11 were constant. It follows that the ratio between current i_3 and i_{p1} varies less by loading. Therefore, the harmonic content of current i_M or the power factor is also less affected by loading.

At a predetermined increased loading condition, the peak value of current i_2 is limited. A further increased loading causes also the peak value of current i_1 to be limited. An even further increased loading, such as a short circuit in the secondary side, results in a burst mode operation in IC 103.



In each cycle of signal V9, when signal V9 of FIGURE 2c attains the HIGH level, capacitor C6 of FIGURE 1 at pin 2 of IC 103 is charged by a current that is equal to a sum of a constant current i_2 , developed via a resistor R2 from voltage V2, and a current i_1 , having a full wave rectified sinusoid waveform, developed via a resistor R1 from voltage V1. When signal V9 of FIGURE 2c is at the LOW level, voltage V6 of FIGURE 2b is clamped to 1 volt, as determined by IC 103 of FIGURE 1. When signal V9 of FIGURE 2c attains the HIGH level, capacitor C6 of FIGURE 1 develops ramping voltage V6, as shown in FIGURE 2b. Because capacitor C6 is charged by means of current i_1 from full wave rectified voltage V1, current i_1 has a similar waveform as that of voltage V1. In IC 103, voltage V6 is coupled to an input of an over-load comparator 103d. When, under over-load condition, voltage V6 is sufficiently large to trigger comparator 103d, a HIGH-to-LOW transition occurs in signal V9. Thus, voltage V6 determines the maximum pulse-width of signal V9 that can be produced under the over-load condition. It follows that voltage V6 determines the maximum power that can be provided by SMPS 100.

In carrying out an inventive feature, the rate of change or peak level of voltage V6 varies during the period of voltage V1 such that when voltage V1 is at a minimum, the upper limit of the pulse-width of signal V9, before an over-load condition occurs, is larger than when voltage V1 is at a maximum. In this way, for a given upper limit of the pulse width of signal V9, occurring at the peak of voltage V1, an even larger pulse-width of the pulse of signal V9 and, therefore, a larger regulation range is obtained remote from the peak of voltage V1.

In IC 103, voltage V6 is coupled to an input of stop comparator 103c. In normal operation, voltage V6, in addition to voltage V30, controls the pulse-width of signal V9. The result is that when voltage V1 is at its peak, voltage V6 causes the pulse-width of signal V9 to be smaller than when voltage V1 is smaller than the peak.

The pulse-width of signal V9 is modulated in a feed-forward manner via voltage V6. Thus, each of sense voltage V30 and the feed-forward voltage contributes to the extent of pulse-



width modulation of signal V9. Advantageously, the feed-forward manner results in a further reduction of the ripple voltage in output voltages V4, V5, V8 and V3.

When SMPS 100 is used in a television receiver, a
5 signal ON/OFF determines when the television receiver is required to operate in a standby mode of operation and when in normal operation mode. The magnitudes of the load coupled to winding W4 and energized by SMPS 100 is determined by on/off control
10 signal ON/OFF, that is produced in, for example, a microprocessor, not shown. Signal ON/OFF is referenced to the cold ground conductor G.

Detection of the standby mode of operation, activated by signal ON/OFF, is performed by a detector 31 that produces an on/off control signal V13 referenced to hot ground conductor H.
15 In the standby mode of operation, the magnitude of the load coupled to windings W4 and W5 is substantially smaller than in normal operation. Because of decreased load an increase in sense voltage V30 tends to occur in the standby mode. Therefore, IC 103 decreases the pulse-width of signal V9. Also, the frequency
20 of signal V9 increases to the resonance frequency of flyback transformer T, around 100 KHz.

Detector 31 is responsive to the pulses in winding W3 that are determined by signal V9 and detects the magnitude of the loads coupled to windings W4 and W5 in accordance with the
25 frequency of the pulses in winding W3. The pulses in winding W3 are coupled, in detector 31, via a low pass filter that is formed by a resistor 32 and a capacitor 33, to a rectifier 34. Thus, rectifier 34 produces in a capacitor 35 a DC voltage representative of the length of the interval between transition edges of the pulses in
30 winding W3.

In the standby mode of operation, winding W3 supplies an almost sinusoidal voltage at 100 KHz. This voltage is attenuated by the low pass filter formed by resistor 32 and capacitor 33. Therefore, the voltage in capacitor 35 becomes
35 insufficiently small to turn-on an output transistor 36 of detector 31. The result is that signal V13 is at the HIGH level. On the other hand, in the normal mode of operation, the frequency is lower and transistor 36 is maintained continuously conductive



and signal V13 is at the LOW level. In this way, frequency detector 31 produces signal V13 referenced to hot ground H that is indicative of standby/normal mode of operation.

Signal V13 is coupled via a diode D14 to the base of transistor Q3. Signal V13 causes transistor Q3 to conduct regardless of the level of signal V9. Therefore, transistor Q2 is turned off, during standby, and current i_{p2} is zero. In this case, DC current flows through resistors R8 and R12 and via transistor Q3 to ground. Resistor R12 that is a positive temperature coefficient resistor heats and increases considerably in value. Thus, the losses in resistor R8 are further decreased, during standby. The overall circuit dissipation is further reduced because transistor Q2 is always turned off, during standby. Using this technique has two advantages. Firstly, standby input power is reduced from 14 watts to 10 watts. Secondly, during Standby, the harmonics are significantly reduced because there is only current i_{p1} current component.

During the standby mode of operation, voltages V3, V4 and V5 are also regulated. However, because of leakage inductance, the ratio between sense voltage V30 and output voltage V4 is such that voltage V4 tends to be larger, in standby, than in normal mode of operation. Such increase in voltage V4 that energizes output stage 37 may be undesirable because of increased component stress.

On/off control signal V13 is coupled via a series arrangement of a resistor 38 and a diode 39 to the sense input terminal, pin 1, of IC 103 for increasing the level of sense voltage V30. As a result, the duty cycle of signal V9 decreases. Consequently, advantageously, voltage V4 is decreased relative to what it would have been without the effect of the signal that is coupled via diode 39. For example, the value of circuit components can be selected in such a way that voltage V4 becomes, in standby, even smaller than in normal mode of operation.

FIGURE 4 illustrates a second embodiment of the invention that is similar to that of FIGURE 1 with the differences noted below. FIGURES 5a-5e illustrate waveforms useful for explaining the operation the circuit of FIGURE 4. Similar symbols



and numerals in FIGURES 1, 2a-2h, 3a-3c, 4 and 5a-5e indicate similar items or functions except that the symbol prime (') is added in FIGURE 4 for the corresponding element. In SMPS 100' of FIGURE 4, transistor Q2' is a bipolar transistor. The base current for transistor Q2' is supplied via a half-wave rectifier diode D8' and a base resistor R8'. Signal V10' is derived from the collector of transistor Q5' and coupled to the base of transistor Q3' via an inverter stage formed by a transistor Q6'. The collector voltage of transistor Q6' is relatively large when turn on of transistor Q3 is required. Therefore, a base resistor 70' may be a relatively large resistor. Advantageously, because resistor 70' may be large, the circuit is less sensitive to tolerances in the level of signal V9' when signal V9' is at the LOW level and transistor Q3' is required to be turned off.

Increased loading causes a larger voltage drop across resistor R13'. Therefore, the base voltage of transistor Q2' also decreases when transistor Q2' is turned on. Advantageously, the base current also increases because of the decrease in the base voltage. The increase in the base current is desirable for maintaining transistor Q2' in saturation when its collector current increases. Signal V13' is coupled to the base of transistor Q6' to turn on transistor Q6' in the standby mode.

When a short circuit condition occurs in the load, not shown, the voltage across winding W3' is zero. Therefore, transistor 36' is turned off. The result is an increase in voltage V30' that tends to decrease the duty cycle of signal V9' so as to provide short circuit protection.

When loading of the power supply becomes smaller than a predetermined value, for example, 80 watts, a diode 200' that is coupled to the base of transistor Q5' clamps the base voltage of transistor Q5' to 4 volts. Thus, the base voltage of transistor Q5' cannot decrease below that level. Therefore, diode 200' establishes a maximum value for the conduction interval or maximum duty cycle of transistor Q2' at low loading. Thus, advantageously, the power factor that is determined by current i3' does not decrease when the loading further decreases. By providing upper limit to the duty cycle of transistor Q2', the value of resistor R13' can be smaller than if the maximum duty cycle of



transistor Q2' could further increase when the load decreases. Therefore, advantageously, the power dissipation in resistor R13' can be made lower than if the clamping operation of diode 200' were not employed. Advantageously, the duty cycle upper
5 limitation of transistor Q2' does not cause an increase in a ripple voltage at the output of the power supply because filter capacitors at the output of the power supply, are sufficiently large to reduce ripple at low loading.

In FIGURE 6, a family of graphs shows the variation of
10 the power factor for different values of resistor R13' of FIGURE 4, as a function of the input power to the power supply. The efficiency factor η at an input power of 100W for different values of resistor R13' is also provided.

In FIGURE 7, a family of graphs shows the harmonics
15 contents of input current IM' of FIGURE 4 when resistor R13' is equal to 22 Ohm and when it is equal to 100 Ohm. For comparison purposes, the maximum allowed harmonics content in what is believed to be the proposed standard is also shown.



CLAIMS

1. A switch mode power supply, comprising:
a source (107) of an AC, mains supply voltage (VM);
an inductance (W1);
5 a first rectifier (102) coupled to said mains source for rectifying said mains supply voltage to apply to said inductance a rectified, first supply voltage (V1);
switching means (Q1) responsive to a switching signal (V9) for generating in said inductance pulse-width modulated
10 current pulses (iP) from said first supply voltage at a frequency (20 KHz) that is substantially higher than a frequency (50 Hz) of said mains supply voltage, said current pulses being coupled from said inductance to a load circuit (37) to energize said load circuit;
a pulse-width modulator (103) responsive to a
15 feedback signal (V30) for generating said switching signal in accordance with said feedback signal; and characterized by
means (103d) coupled to said pulse-width modulator and responsive to said mains supply voltage for limiting a pulse-width of said switching signal such that a limit associated with
20 said pulse-width varies during a period of said mains supply voltage in accordance with a waveform (V1) of said mains supply voltage.
2. A power supply according to Claim 1 characterized
25 in that said main supply voltage (VM) is coupled to said pulse-width limiting means via a signal path (R1) that bypasses said inductance (W1) in a feed forward manner for varying said limit.
3. A power supply according to Claim 1 characterized
30 in that, during said period (20 msec), an increase in a magnitude of said mains supply voltage (VM) causes said limit associated with a pulse width of a given current pulse of said current pulses to decrease, and vice verse.
- 35 4. A power supply according to Claim 1 characterized in that said limit shifts to a higher value remotely from a peak of said main supply voltage (VM).



5. A power supply according to Claim 1 characterized in that said pulse-width modulator (103) is responsive to said main supply voltage (VM) for modulating said switching signal in accordance with said main supply voltage in a feed-forward manner when said pulse width is smaller than said limit.

This Sheet Has Been Replaced



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